

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSIII)

SSM6P25TU

High Speed Switching Applications

- Optimum for high-density mounting in small packages
- Low on-resistance: $R_{on} = 260m\Omega$ (max) (@ $V_{GS} = -4$ V)
 $R_{on} = 430m\Omega$ (max) (@ $V_{GS} = -2.5$ V)

Absolute Maximum Ratings ($T_a = 25^\circ C$) (Q1, Q2 Common)

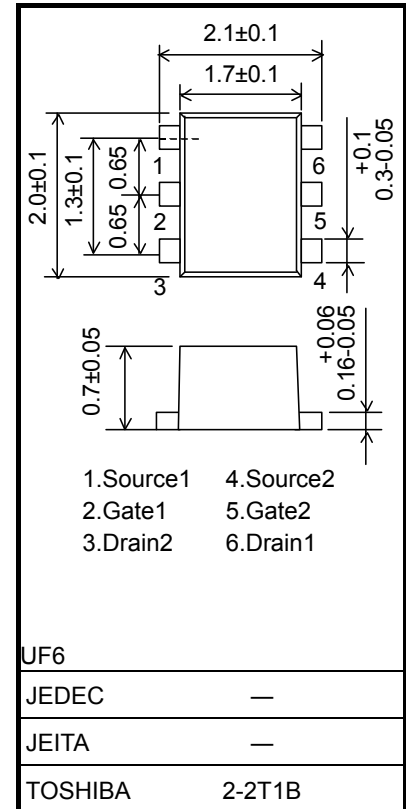
Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V_{DS}	-20	V
Gate-Source voltage		V_{GSS}	± 12	V
Drain current	DC	I_D	-0.5	A
	Pulse	I_{DP}	-1.5	
Drain power dissipation		P_D (Note 1)	500	mW
Channel temperature		T_{ch}	150	$^\circ C$
Storage temperature range		T_{stg}	-55~150	$^\circ C$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

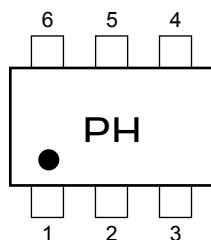
Note 1: Mounted on FR4 board. (total dissipation)
 (25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 645 mm²)

Unit: mm

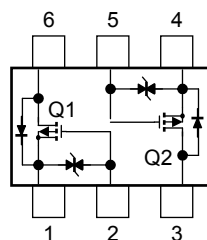


Weight: 7.0 mg (typ.)

Marking



Equivalent Circuit (top view)



Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

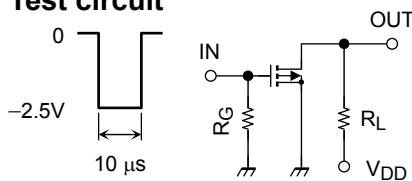
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit	
Gate leakage current	I_{GSS}	$V_{GS} = \pm 12V, V_{DS} = 0$	—	—	± 1	μA	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D = -1 mA, V_{GS} = 0$	-20	—	—	V	
	$V_{(BR)DSX}$	$I_D = -1 mA, V_{GS} = +12 V$	-8	—	—		
Drain cut-off current	I_{DSS}	$V_{DS} = -20 V, V_{GS} = 0$	—	—	-1	μA	
Gate threshold voltage	V_{th}	$V_{DS} = -3 V, I_D = -0.1 mA$	-0.5	—	-1.1	V	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -3 V, I_D = -0.25 A$ (Note2)	0.65	1.3	—	S	
Drain-Source on-resistance	$R_{DS(ON)}$	$I_D = -0.25 A, V_{GS} = -4 V$ (Note2)	—	210	260	m Ω	
		$I_D = -0.25 A, V_{GS} = -2.5 V$ (Note2)	—	310	430		
Input capacitance	C_{iss}	$V_{DS} = -10 V, V_{GS} = 0, f = 1 MHz$	—	218	—	pF	
Reverse transfer capacitance	C_{rss}	$V_{DS} = -10 V, V_{GS} = 0, f = 1 MHz$	—	42	—	pF	
Output capacitance	C_{oss}	$V_{DS} = -10 V, V_{GS} = 0, f = 1 MHz$	—	52	—	pF	
Switching time	Turn-on time	t_{on}	$V_{DD} = -10 V, I_D = -0.25 A,$	—	16	—	ns
	Turn-off time						

Note2: Pulse test

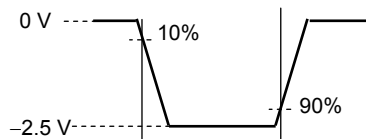
Switching Time Test Circuit

(a) Test circuit

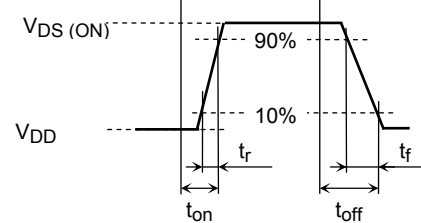


$V_{DD} = -10 V$
 $R_G = 4.7 \Omega$
 D.U. $\leq 1\%$
 $V_{IN}: t_r, t_f < 5 ns$
 Common Source
 $T_a = 25^\circ C$

(b) V_{IN}



(c) V_{OUT}

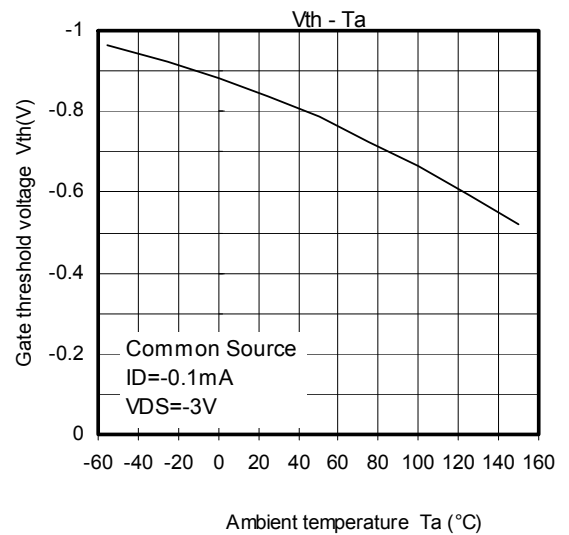
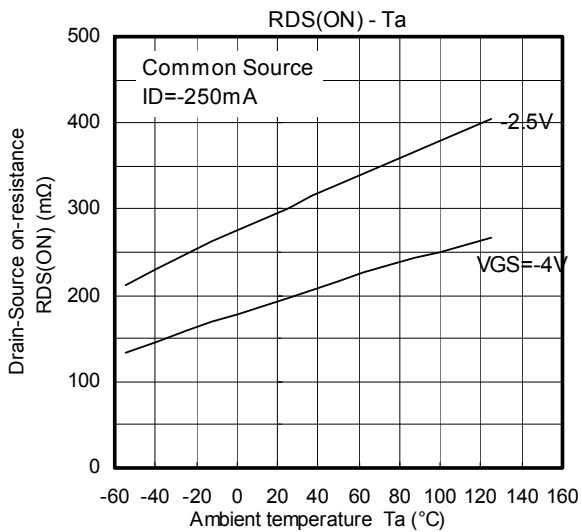
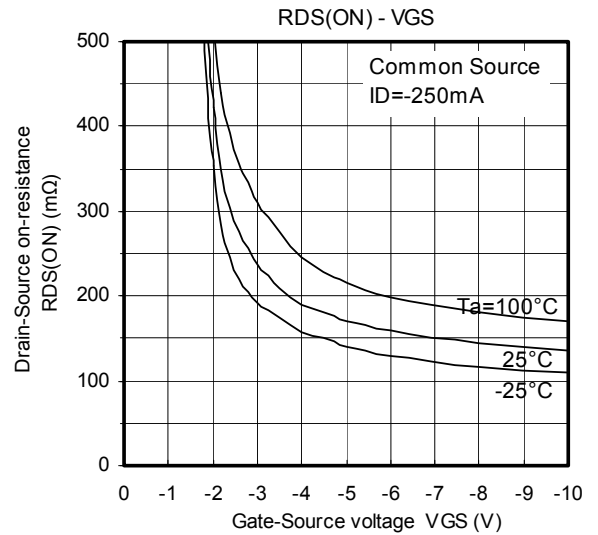
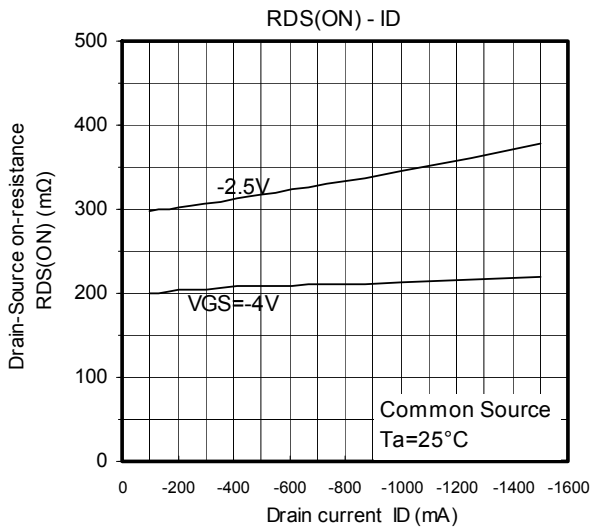
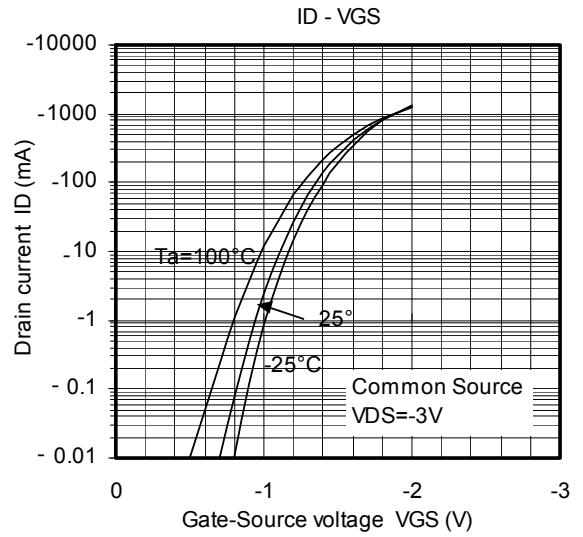
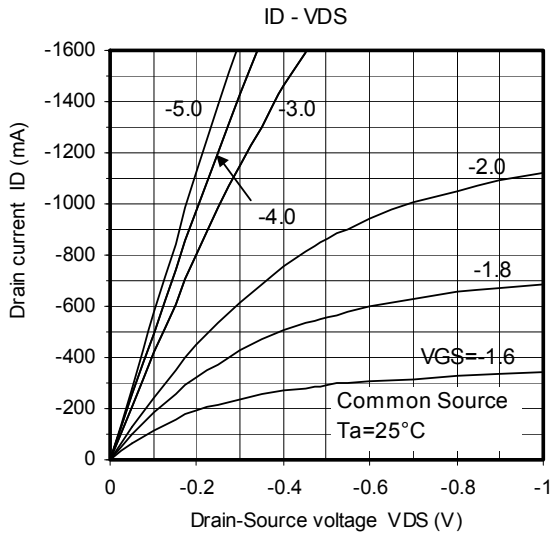


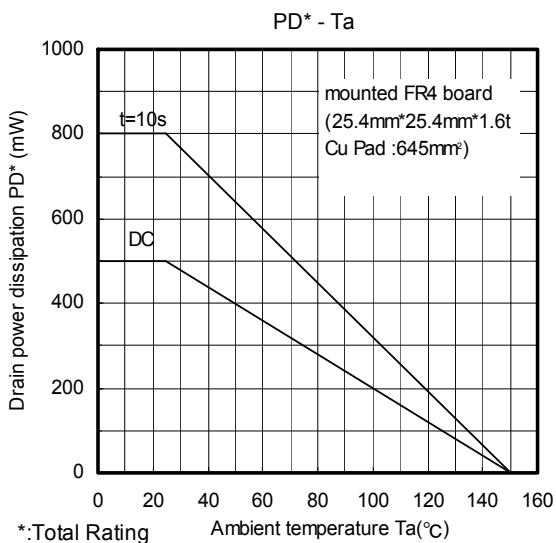
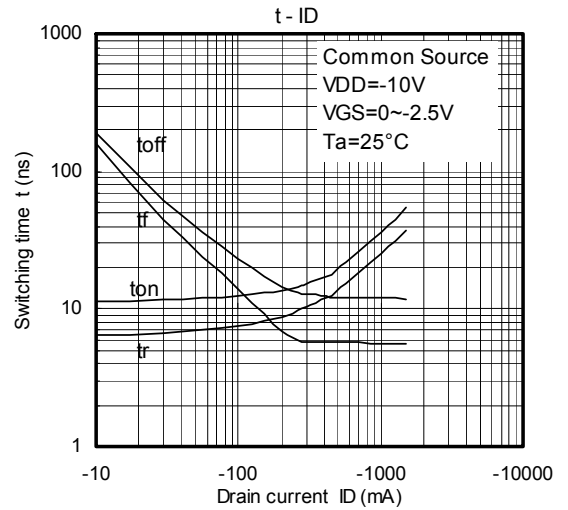
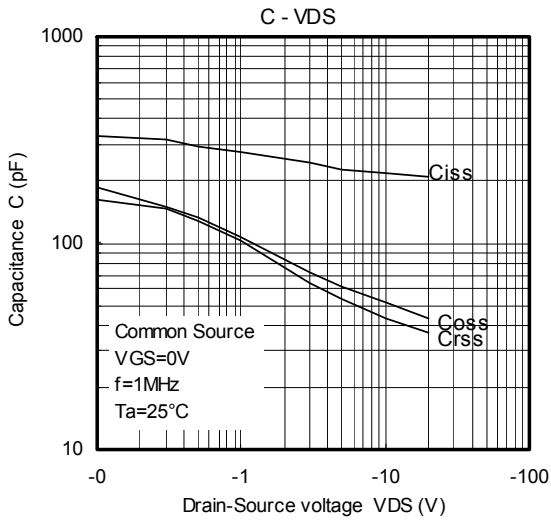
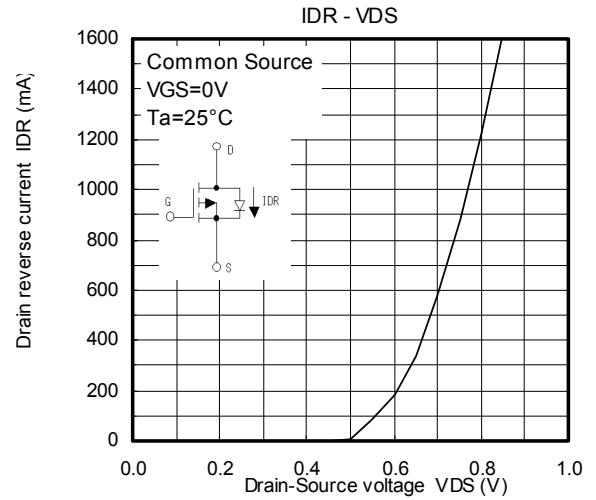
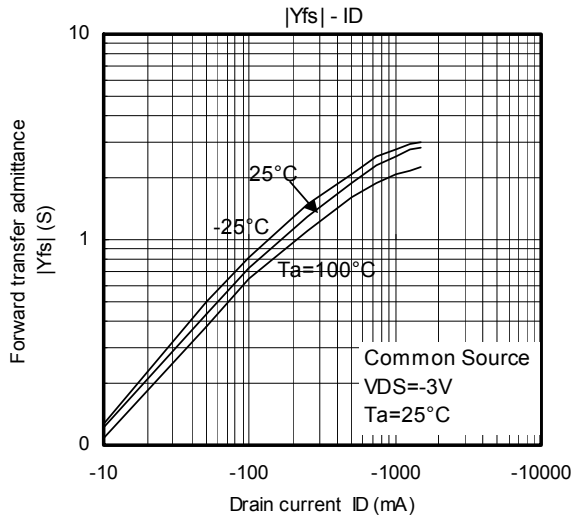
Precaution

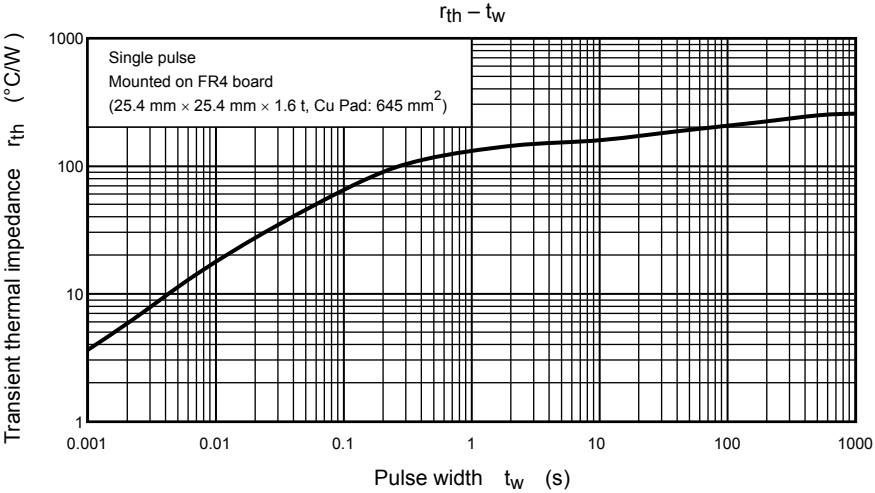
V_{th} can be expressed as the voltage between gate and source when the low operating current value is $I_D = -100 \mu A$ for this product. For normal switching operation, $V_{GS(ON)}$ requires a higher voltage than V_{th} and $V_{GS(OFF)}$ requires a lower voltage than V_{th} .

(The relationship can be established as follows: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$)

Please take this into consideration when using the device.







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20070701-EN GENERAL

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